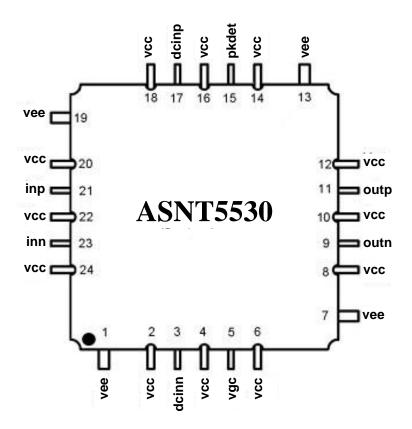
ASNT5530-KMC DC-45*Gbps* Limiting Amplifier

- Broadband limiting amplifier with adjustable gain, output peaking, and offset controls
- Low jitter and limited temperature variation over industrial temperature range
- 23GHz of analog bandwidth in limiting mode
- On-chip input peak detector
- Fully differential CML-type input interface
- Fully differential CML output interface with 300mV single-ended swing
- Single +3.3V or -3.3V power supply
- Power consumption: 340mW
- Fabricated in SiGe for high performance, yield, and reliability
- Custom CQFP 24-pin package



www.fulai-elec.com

DESCRIPTION

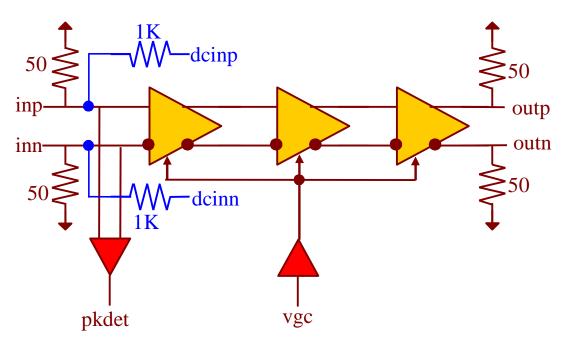


Fig. 1. Functional Block Diagram

The temperature stable ASNT5530-KMC SiGe IC provides low jitter broadband variable signal amplification between its input and output signal ports and is intended for use in high-speed communication systems. The circuit shown in Fig. 1 accepts an analog signal at its input differential port inp/inn and delivers a voltage-limited output signal at the output differential port outp/outn. The common-mode voltage levels of input signals can be adjusted using analog control inputs dcinp/dcinn. The total gain can be externally adjusted through the gain control port vgc. The input amplitude can be monitored using the analog output voltage pkdet.

The part's I/Os support the CML logic interface with on chip 50*Ohm* termination to **vcc** and may be used differentially, AC/DC coupled, single-ended, or in any combination (see also POWER SUPPLY CONFIGURATION). In the DC-coupling mode, the input signal's common mode voltage should comply with the specifications shown in ELECTRICAL CHARACTERISTICS. In the AC-coupling mode, the input termination provides the required common mode voltage automatically. The differential DC signaling mode is recommended for optimal performance.

POWER SUPPLY CONFIGURATION

The part can operate with either a negative supply (vcc = 0.0V=ground and vee = -3.3V), or a positive supply (vcc = +3.3V and vee = 0.0V=ground). In case of the positive supply, all I/Os need AC termination when connected to any devices with 50Ohm termination to ground. Different PCB layouts will be needed for each different power supply combination.

All the characteristics detailed below assume vcc = 0.0V and vee = -3.3V.

ABSOLUTE MAXIMUM RATINGS

Caution: Exceeding the absolute maximum ratings shown in Table 1 may cause damage to this product and/or lead to reduced reliability. Functional performance is specified over the recommended operating conditions for power supply and temperature only. AC and DC device characteristics at or beyond the absolute maximum ratings are not assumed or implied. All min and max voltage limits are referenced to ground (assumed vcc).

Table 1. Absolute Maximum Ratings

Parameter	Min	Max	Units
Supply Voltage (vee)		-3.6	V
Power Consumption		0.4	W
RF Input Voltage Swing (SE)		1.0	V
Case Temperature		+90	°C
Storage Temperature	-40	+100	°C
Operational Humidity	10	98	%
Storage Humidity	10	98	%

TERMINAL FUNCTIONS

TE	RMIN	AL		DESCRIPTION		
Name	No.	Type				
	High-Speed I/Os					
inp	21	CML	Differential data inputs with internal SE 50 <i>Ohm</i> termination to vcc			
inn	23	input				
outp	11	CML	Differential high-speed signal outputs with internal SE 500hm			
outn	9	output	termination to vcc. Require external SE 500hm termination to vcc			
dcinp	17	Analog	inp common mode control voltage			
dcinn	3	inputs	inn common mode control voltage			
vgc	5	Analog	Gain control voltage			
		input				
pkdet	15	Analog	Analog voltage representing input signal's amplitude			
		output				
	Supply And Termination Voltages					
Name	ne Description			Pin Number		
vcc	Posit	ositive power supply $(+3.3V \text{ or } 0)$		2, 4, 6, 8, 10, 12, 14, 16, 18, 20, 22, 24		
vee	Negative power supply $(0V \text{ or } -3.3V)$		r supply (0 <i>V</i> or -3.3 <i>V</i>)	1, 7, 13, 19		

ELECTRICAL CHARACTERISTICS

PARAMETER	MIN	TYP	MAX	UNIT	COMMENTS	
General Parameters						
vee	-3.1	-3.3	-3.5	V	±6%	
vcc		0.0		V	External ground	
<i>I</i> vee		103		mA		
Power consumption		340		mW		
Junction temperature	-25	50	125	$^{\circ}C$		
		,	Input (inp	/inn)		
Data Rate	0		45	Gbps		
Swing	10	200	500	mV	Differential or SE, p-p	
CM Voltage Level	vcc-0.6	vcc-0.15	vcc+0.3	V	Must match for both inputs	
	Output (outp/outn)					
Data Rate	0		45	Gbps		
Logic "1" level	VCC		V			
Logic "0" level	vcc-0.15		V	With external 50 <i>Ohm</i> DC termination		
Rise/Fall Times	10	12	14	ps	20%-80%	
Additive Jitter			1	ps	Peak-to-peak	
Gain Control Port (vgc)						
Bandwidth	0.0		100	MHz		
Input Signal Range	-1.0		0.0	V		
Gain Variation	32	35	38	dB	< ±5%	
Common Mode Control Ports (dcinp/dcinn)						
Input Signal Range	-3.3		0.0	V		
Peak Detector Output (pkdet)						
Bandwidth	0.0		1.0	KHz		
Output Signal Range	-1.0		0.0	V		

PACKAGE INFORMATION

The chip die is housed in a custom 24-pin CQFP package shown in Fig. 2. The package provides a center heat slug located on its back side to be used for heat dissipation. ADSANTEC recommends for this section to be soldered to the vcc plain, which is ground for a negative supply, or power for a positive supply.

The part's identification label is ASNT5530-KMC. The first 8 characters of the name before the dash identify the bare die including general circuit family, fabrication technology, specific circuit type, and part version while the 3 characters after the dash represent the package's manufacturer, type, and pin out count.

The IC complies with the Restriction of Hazardous Substances (RoHS) per EU 2002/95/EC for all 6 substances.

Ultra High-Speed Mixed Signal AS/Cs 6444-1515 Offices: 310-377-6029 / 310-803-9284 Fax: 310-377-9940 sales@fulai-elec.com www.adsantec.com

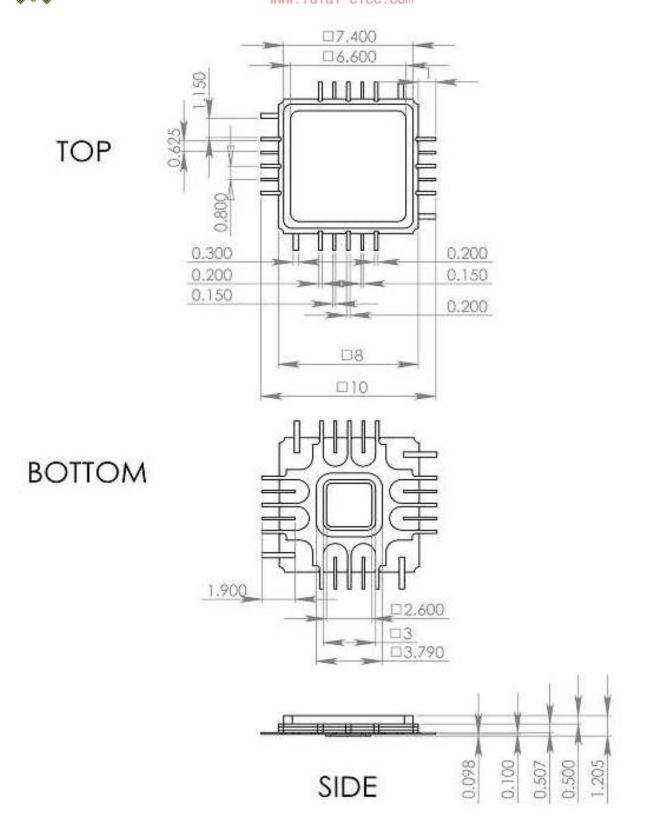


Fig. 2. CQFP 24-Pin Package Drawing (All Dimensions in mm)

Rev.1.1.1 5 January 2016

REVISION HISTORY

Revision	Date	Changes		
1.1.1	01-2016	Updated Formatting		
1.0.1	02-2014	Initial Release		